
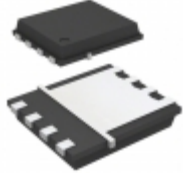
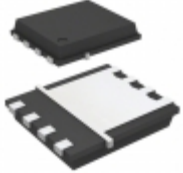
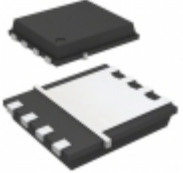

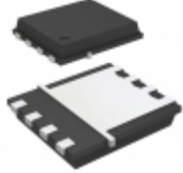
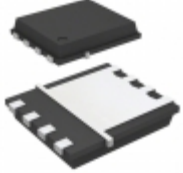
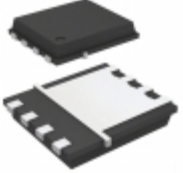
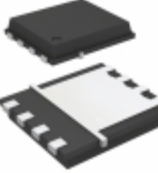
	<h2 style="color: #E67E22;">FDMS0310S</h2>
	<p>Hersteller-Teilenummer: FDMS0310S</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 30V 19A</p> <p>Datenblätter:  FDMS0310S.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 136250 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FDMS0310S
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 30V 19A
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	136250 pcs Stock
Hersteller Standard Vorlaufzeit	26 Weeks
detaillierte Beschreibung	N-Channel 30V 19A (Ta), 42A (Tc) 2.5W (Ta), 46W
Serie	PowerTrench®, SyncFET™
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-PowerTDFN
Supplier Device-Gehäuse	8-PQFN (5x6)
Verlustleistung (max)	2.5W (Ta), 46W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	19A (Ta), 42A (Tc)
Rds On (Max) @ Id, Vgs	4 mOhm @ 18A, 10V
VGS (th) (Max) @ Id	3V @ 1mA
Gate Charge (Qg) (Max) @ Vgs	46nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	2820pF @ 15V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	FDMS0310STR







FDMS0310S ist neu im Original. Suche FDMS0310S Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FDMS0310S AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FDMS0310S: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FDMS030N06B AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 22.1A POWER56</p>	 <p>FDMS0312S AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 19A POWER56</p>	 <p>FDMS0312AS AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 18A PT8</p>	 <p>FDMS0343S Fairchild FDMS0343S Fairchild</p>
 <p>FDMS0312S Fairchild/ON Semiconductor MOSFET N-CH 30V 19A POWER56</p>	 <p>FDMS0312AS Fairchild/ON Semiconductor MOSFET N-CH 30V 18A PT8</p>	 <p>FDMS0310S Fairchild/ON Semiconductor MOSFET N-CH 30V 19A</p>	 <p>FDMS0310AS AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 19A PT8</p>

heiße Teile

Mehr

 FDMQ8203	 FDMS0300S	 FDMS0306S	 FDMS0308S	 FDMS015N04B
 FDMS0306AS	 FDMS0308CS	 FDMS0308CS	 FDMS0306S	 FDMS0302S
 FDMS0308AS	 FDMS030N06B	 FDMS030N06B	 FDMS0310AS	 FDMS0308AS
 FDMS0309AS	 FDMS0312AS	 FDMS0312AS	 FDMS0312S	 FDMS0309AS
 FDMS0310S	 FDMS0346	 FDMS0348	 FDMS0349	 FDMS0310AS
 FDMS0343S	 FDMS0354S	 FDMS0355AS	 FDMS0364S	 FDMS0312S
 FDMS0352S	 FDMS039N08B	 FDMS039N08B	 FDMS0364S	 FDMS0351S
 FDMS037N08B	 FDMS2506SDC	 FDMS2572	 FDMS2380	 FDMS037N08B
FDMS2506SDC			FDMS2572	 FDMS2380
				 FDMS2672

Contact us:Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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